

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re the Application of

Inventor: Yukihiro INOUE

Group Art Unit: 2811

Appln. No.: 09/768,556

Examiner: S. Gebremariam

Filed: January 25, 2001

For: SEMICONDUCTOR DEVICE

FAX RECEIVED

JAN 8 - 2003

TECHNOLOGY CENTER 2800

AMENDMENT

Assistant Commissioner of Patents
Washington, D.C. 20231

Sir:

Please amend the above-captioned application as follows:

IN THE CLAIMS:

Please cancel claims 9 and 10, without prejudice or disclaimer.

Please amend the claims to read as follows (Exhibit I contains a marked up version):

5. (Twice Amended) A semiconductor device according to claim 13 wherein said diffusion layer of the first conductivity type is a channel stopper region.

6. (Twice Amended) A semiconductor device according to claim 14 wherein said diffusion layer of the first conductivity type is a channel stopper region.